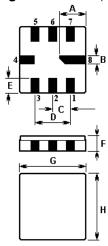


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Email: info@actcrystals.com

The ACTQ964/868.3/QCC8C is a two-port, 180° surface-acoustic-wave (SAW) resonator in a surface-mount ceramic QCC8C case. It provides reliable, fundamental-mode, quartz frequency stabilization i.e. in transmitters or local oscillators operating at 868.300 MHz.

# 1.Package Dimension (QCC8C)

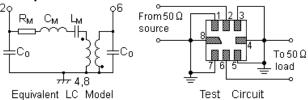


#### 2

Pin	Configuration
2	Input / Output
6	Input / Output
4,8	Case Ground
1,3,5,7	NC

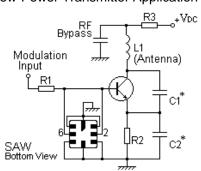
Sign	Data (unit: mm)	Sign	Sign Data (unit: mm)		
Α	2.08	Е	1.2		
В	0.6	F	1.35		
С	1.27	G	5.0		
D	2.54	Н	5.0		

### 3. Equivalent LC Model and Test Circuit

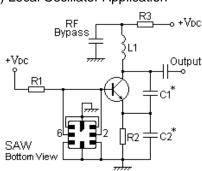


# 4. Typical Application Circuits

# 1) Low-Power Transmitter Application



# 2) Local Oscillator Application



In keeping with our ongoing policy of product evolvement and improvement, the above specification is subject to change without notice.

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For quotations or further information please contact us at:

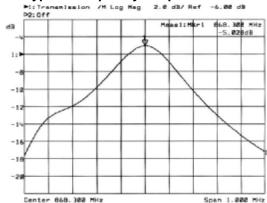
3 The Business Centre, Molly Millars Lane, Wokingham, Berks, RG41 2EY, UK

Issue: 1 C1

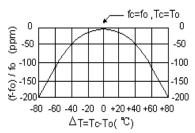


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#### 5. Typical Frequency Response



# **6.Temperature Characteristics**



The curve shown above accounts for resonator contribution only and does not include LC component temperature characteristics.

#### 7.Performance

# 7-1.Maximum Ratings

Rating	Value	Units
CW RF Power Dissipation	10	dBm
DC Voltage Between Terminals	±30V	VDC
Case Temperature	-40 to +85	°C
Soldering Temperature	+250	°C

### 7-2. Electronic Characteristics

7 Z.Eloctorio Oriatoteriolo									
	Characteristics	Sym	Minimum	Typical	Maximum	Units			
Centre Frequency (+25 °C)	Absolute Frequency	f <sub>C</sub>	868.150		868.450	MHz			
	Tolerance from 868.300 MHz	$\Delta f_{C}$		±150		kHz			
Insertion Loss		IL		5.5	8.0	dB			
Quality Factor	Unloaded Q	Q <sub>U</sub>		6,820					
	50 Ω Loaded Q	$Q_L$		3,200					
Temperature Stability	Turnover Temperature	T <sub>0</sub>	25		55	°C			
	Turnover Frequency	f <sub>0</sub>		fc		kHz			
	Frequency Temperature Coefficient	FTC		0.03		ppm/°C 2			
Frequency Aging - Absolute Value during the First Year		f <sub>A</sub>		≤10		ppm/yr			
DC Insulation Resistance Between Any Two Terminals			1.0			ΜΩ			
RF Equivalent RLC Model	Motional Resistance	R <sub>M</sub>		88.365	151	Ω			
	Motional Inductance	L <sub>M</sub>		110.5403		μН			
	Motional Capacitance	См		0.3042		fF			
	Shunt Static Capacitance	Co	1.20	1.45	1.70	pF			

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Issue: 1 C1

Date: SEPT 04

Email: info@actcrystals.com

# i CAUTION: Electrostatic Sensitive Device. Observe precautions for handling!

- 1. The frequency f<sub>C</sub> is the frequency of minimum IL with the resonator in the specified test fixture in a 50 Ω test system with VSWR≤1.2:1.
- 2. Unless noted otherwise, case temperature  $T_C = +25^{\circ}C \pm 2^{\circ}C$ .
- Frequency aging is the change in f<sub>C</sub> with time and is specified at +65°C or less. Aging may exceed the specification for prolonged temperatures above +65°C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
- 4. Turnover temperature,  $T_0$ , is the temperature of maximum (or turnover) frequency,  $f_0$ . The nominal frequency at any case temperature,  $T_0$ , may be calculated from:  $f = f_0 [1 FTC (T_0 T_0)^2]$ .
- 5. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C<sub>0</sub> is the measured static (non-motional) capacitance between input terminal and ground or output terminal and ground. The measurement includes case parasitic capacitance.
- 6. Derived mathematically from one or more of the following directly measured parameters: f c, IL, 3 dB bandwidth, fc versus Tc, and Co.
- The specifications of this device are based on the test circuit shown above and subject to change or obsolescence without notice.
- 8. Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- 9. Our liability is only assumed for the Surface Acoustic Wave (SAW) component(s) per se, not for applications, processes and circuits implemented within components or assemblies.

In keeping with our ongoing policy of product evolvement and improvement, the above specification is subject to change without notice.

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